

I-V curve of NNN structure & RC filter

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Introduction

In this project we calculated I-V curve of two different structure.

(1) 600-nm-long version (Long)

– 100 nm: Highly doped ($5 \times 10^{17} \text{ cm}^{-3}$)

– 400 nm: Lowly doped ($2 \times 10^{15} \text{ cm}^{-3}$)

– 100 nm: Highly doped ($5 \times 10^{17} \text{ cm}^{-3}$)

(2) 120-nm-long version (Short)

– 40 nm: Highly doped ($5 \times 10^{19} \text{ cm}^{-3}$)

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Also for second project we calculated current of RC circuit and compare it with analytical model.

R: 2 M ohm

C: 5 pF

Result

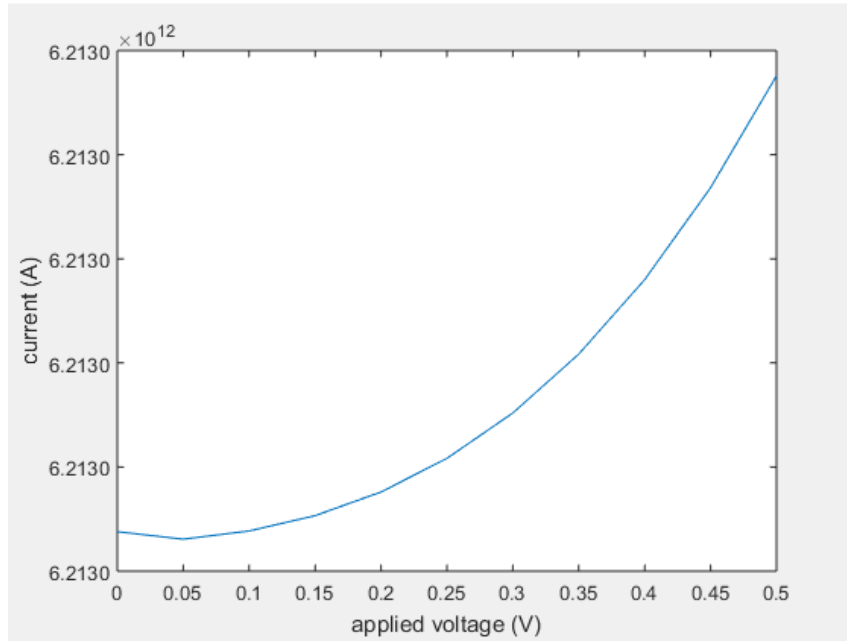


Figure 1. 600-nm-long version (Long)

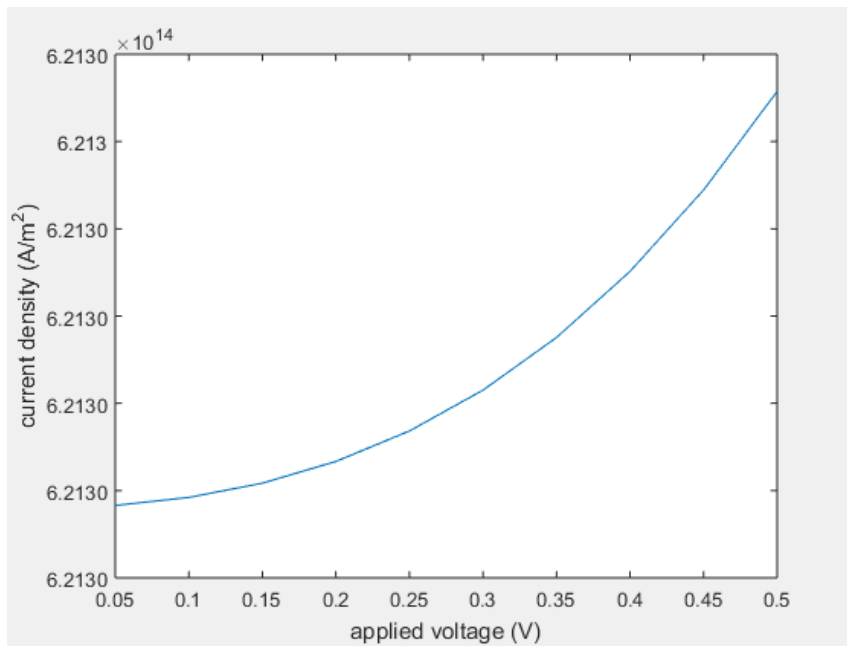


Figure 2. 120-nm-long version (Short)

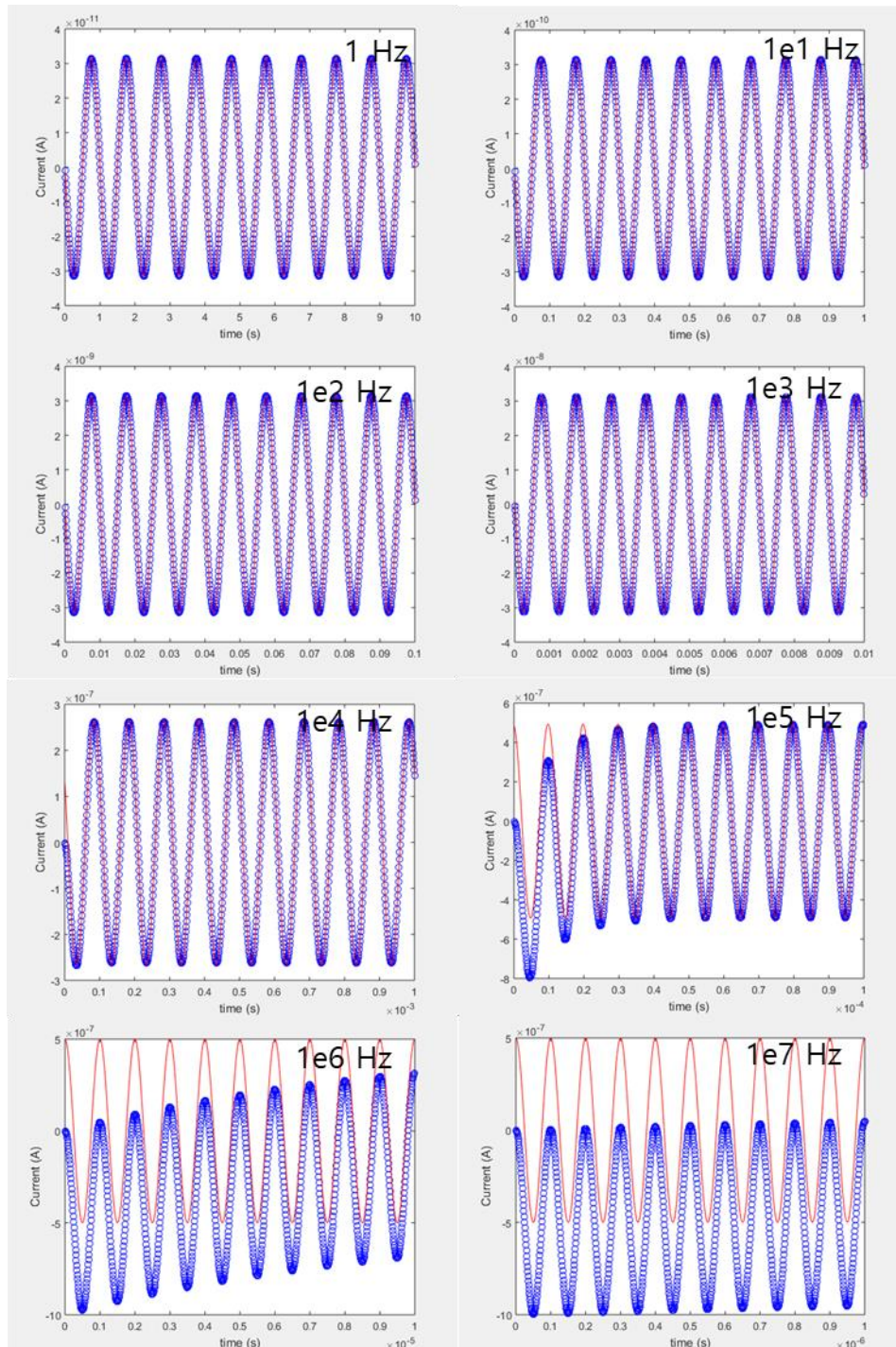


Figure 3. Current of RC circuit with respect to the frequency